



30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

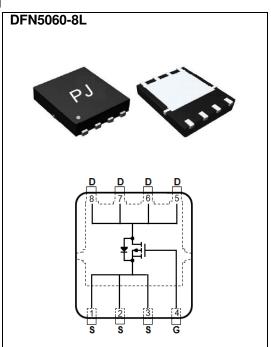
-45 A

Features

- R_{DS(ON)}, V_{GS}@-10V,I_D@-10A<15.5mΩ
- $R_{DS(ON)}$, V_{GS} @-4.5V, I_D @-6A<23 $m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	-30	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _C =25°C	- I _D	-45	А	
	T _C =100°C		-28		
Pulsed Drain Current ^(Note 1)	T _C =25°C	I _{DM}	-180		
Power Dissipation	T _C =25°C	Po	40	14/	
	T _C =100°C		16	W	
Continuous Drain Current	T _A =25°C	I _D	-10	Δ.	
	T _A =70°C		-8	A	
Power Dissipation	T _A =25°C	D-	2.0	14/	
Power Dissipation	T _A =70°C	Po	1.3	W	
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	$R_{ heta JC}$	3.1	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V,I _D =-250uA	-30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250$ uA	-1.0	-1.6	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V,I _D =-10A	-	12	15.5	mΩ
		V _{GS} =-4.5V,I _D =-6A	-	18	23	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-30V, V_{GS} =0V	-	-	-1.0	uA
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Q_g	V_{DS} =-15V, I_{D} =-8A, V_{GS} =-4.5V ^(Note 1,2)	-	14	-	nC
Gate-Source Charge	Q_gs		-	4.6	-	
Gate-Drain Charge	Q_gd		-	5.4	-	
Input Capacitance	Ciss	V _{DS} =-15V, V _{GS} =0V, f=1.0MH <i>Z</i>	-	1556	-	pF
Output Capacitance	Coss		-	243	-	
Reverse Transfer Capacitance	Crss	I=1.UIVIIIZ	-	175	-	
Turn-On Delay Time	td _(on)	\/ 45\/ 4A	-	7.3	-	
Turn-On Rise Time	t _r	V_{DD} =-15V, I_{D} =-1A, V_{GS} =-10V, R_{G} =6 Ω (Note 1,2)	-	13	-	ns
Turn-Off Delay Time	td _(off)		-	88	-	
Turn-Off Fall Time	t _f		-	48	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	ı				-45	Α
Diode Forward Current	I _S		-	-	-40	A
Diode Forward Voltage	V_{SD}	I _S =-1A,V _{GS} =0V	-	-0.7	-1	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing





TYPICAL CHARACTERISTIC CURVES

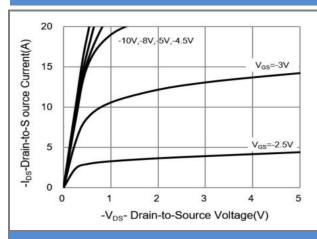


Fig.1 On-Region Characteristics

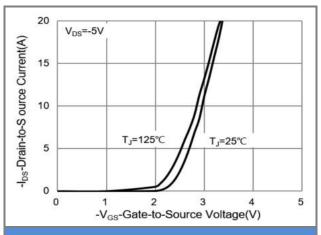


Fig.2 Transfer Characteristics

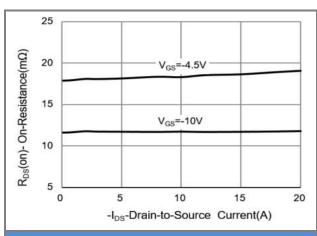


Fig.3 On-Resistance vs. Drain Current

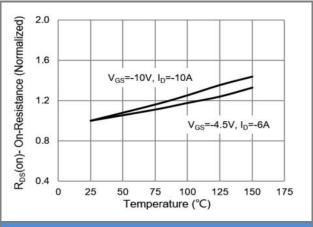


Fig.4 On-Resistance vs. Junction temperature

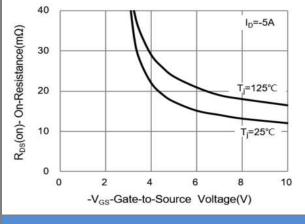


Fig.5 On-Resistance Variation with VGS.

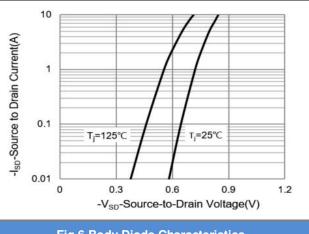


Fig.6 Body Diode Characteristics





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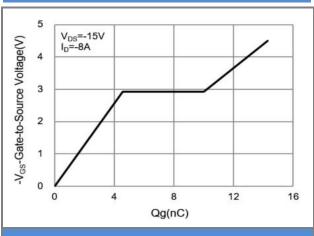


Fig.7 Gate-Charge Characteristics

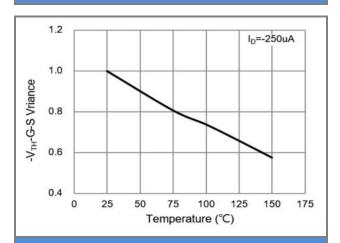


Fig.9 Threshold Voltage Variation with Temperature.

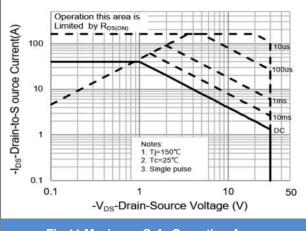


Fig.11 Maximum Safe Operating Area

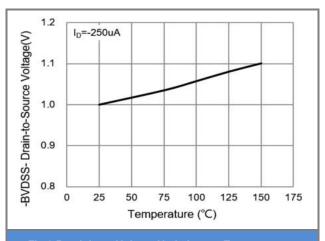


Fig.8 Breakdown Voltage Variation vs. Temperature

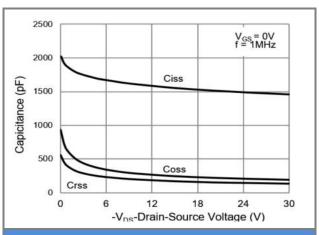


Fig.10 Capacitance vs. Drain-Source Voltage.





TYPICAL CHARACTERISTIC CURVES

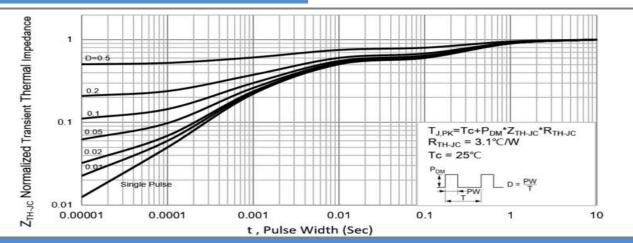


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

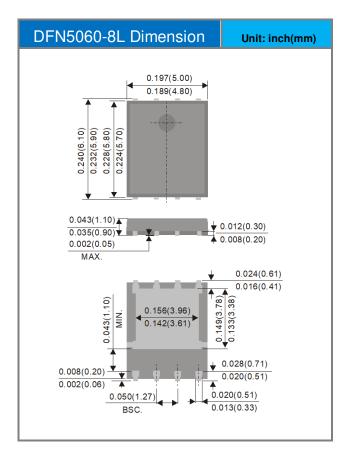


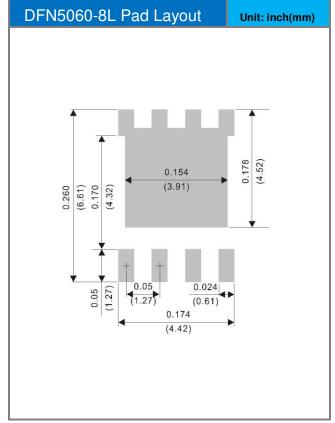


Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ5411_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5411	Halogen free

Packaging Information & Mounting Pad Layout









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